

# UNISONIC TECHNOLOGIES CO., LTD

### MJE13005

#### NPN SILICON TRANSISTOR

# NPN SILICON POWER TRANSISTORS

#### DESCRIPTION

These devices are designed for high-voltage, high-speed power switching inductive circuits where fall time is critical. They are particularly suited for 115 and 220 V SWITCHMODE.

#### **■ FEATURES**

- \* V<sub>CEO(SUS)</sub>= 400 V
- \* Reverse bias SOA with inductive loads @ T<sub>C</sub> = 100°C
- \* Inductive switching matrix 2 to 4 Amp, 25 and 100°C t<sub>C</sub> @ 3A, 100°C is 180 ns (Typ)
- \* 700V blocking capability
- \* SOA and switching applications information

#### **■** APPLICATIONS

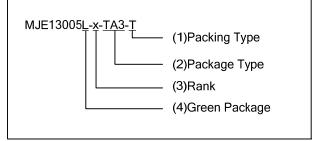
- \* Switching regulator's, inverters
- \* Motor controls
- \* Solenoid/Relay drivers
- \* Deflection circuits

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#### ■ ORDERING INFORMATION

Ordering	Ordering Number		Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MJE13005L-x-TA3-T	MJE13005G-x-TA3-T	TO-220	В	С	Е	Tube	
MJE13005L-x-TF3-T	MJE13005G-x-TF3-T	TO-220F	В	С	Е	Tube	
MJE13005L-x-TM3-T	MJE13005G-x-TM3-T	TO-251	В	С	Е	Tube	
MJE13005L-x-TMS-T	MJE13005G-x-TMS-T	TO-251S	В	С	E	Tube	
MJE13005L-x-TMS2-T	MJE13005G-x-TMS2-T	TO-251S2	В	С	E	Tube	
MJE13005L-x-TMS4-T	MJE13005G-x-TMS4-T	TO-251S4	В	С	E	Tube	
MJE13005L-x-TN3-R	MJE13005G-x-TN3-R	TO-252	В	С	Е	Tape Reel	
MJE13005L-x-TND-R	MJE13005G-x-TND-R	TO-252D	В	С	Е	Tape Reel	
MJE13005L-x-T2Q-T	MJE13005G-x-T2Q-T	TO-262	В	С	Е	Tube	
MJE13005L-x-TQ3-T	MJE13005G-x-TQ3-T	TO-263	В	С	E	Tube	
MJE13005L-x-TQ3-R	MJE13005G-x-TQ3-R	TO-263	В	С	Е	Tape Reel	
MJE13005L-x-T60-K	MJE13005G-x-T60-K	TO-126	В	С	Е	Bulk	
MJE13005L-x-T6S-K	MJE13005G-x-T6S-K	TO-126S	В	С	Е	Bulk	

Note: Pin Assignment: B: Base C: Collector E: Emitter



- (1) T: Tube, K: Bulk, R: Tape Reel
- (2) TA3: TO-220, TF3: TO-220F,TM3: TO-251, TMS: TO-251S, TMS2: TO-251S2,

TMS4:TO-251S4, TN3: TO-252, TND: TO-252D, T2Q: TO-262, TQ3: TO-263, T60: TO-126,

T6S: TO-126S

- (3) x: refer to Classification of hFE1
- (4) L: Lead Free, G: Halogen Free and Lead Free

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#### **■** MARKING

PACKAGE		MARKING		
TO-220 TO-220F TO-251 TO-251S TO-251S2	TO-251S4 TO-252 TO-252D TO-262 TO-263	UTC  MJE13005  C: Lead Free  G: Halogen Free  Lot Code  Data Code		
TO-126 TO-126S		UTC Data Code  MJE13005  L: Lead Free  1  G: Halogen Free		

#### ■ ABSOLUTE MAXIMUM RATINGS

PARAMET	SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage	$V_{CEO(SUS)}$	400	V	
Collector-Emitter Voltage (V <sub>BE</sub> =0)	$V_{CES}$	700	V	
Collector-Base Voltage	$V_{CBO}$	700	V	
Emitter Base Voltage		$V_{EBO}$	9	V
Collector Current	Continuous	I <sub>C</sub>	4	Α
Collector Current	Peak (1)	I <sub>CM</sub>	8	Α
Base Current	Continuous	$I_{B}$	2	Α
Base Current	Peak (1)	I <sub>BM</sub>	4	Α
Emitter Current	Continuous	Ι <sub>Ε</sub>	6	Α
Emiller Current	Peak (1)	I <sub>EM</sub>	12	Α
Power Dissipation at T <sub>A</sub> =25°C	TO-126/TO-126S TO-220F		40	
	TO-251/TO-251S TO-251S2/TO-251S4 TO-252/TO-252D		50	W
	TO-220/TO-263 TO-262	P <sub>D</sub>	75	
	TO-126/TO-126S TO-220F		320	
Derate above 25°C	TO-251/TO-251S TO-251S2/TO-251S4 TO-252/TO-252D		400	mW/°C
	TO-220/TO-263 TO-262		600	
Operating and Storage Junction T	$T_J,T_STG$	-65 ~ +150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ THERMAL DATA

PARAM	METER	SYMBOL	RATINGS	UNIT	
	TO-126/TO-126S		89		
	TO-251/TO-251S	θ <sub>ЈА</sub>	110	°C/W	
Junction to Ambient	TO-251S2/TO-251S4				
Junction to Ambient	TO-252/TO-252D				
	TO-220/TO-263		62.5		
	TO-262/TO-220F				
	TO-126/TO-126S		3.125	°C/W	
	TO-220F TO-251/TO-251S TO-251S2/TO-251S4 TO-252/TO-252D TO-220/TO-263		3.125		
		$ heta_{ extsf{JC}}$	2.5		
Junction to Case					
			1.67		
	TO-262		1.07		

#### ■ **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFF CHARACTERISTICS (Note 1)							
Collector-Emitter Sustaining Voltage	V <sub>CEO(SUS)</sub>	I <sub>C</sub> =10mA , I <sub>B</sub> =0 400				V	
		V <sub>CBO</sub> =Rated Value,			1		
Calla star Cutoff Current		V <sub>BE(OFF)</sub> =1.5V				Л	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CBO</sub> =Rated Value,			E	mA	
		V <sub>BE(OFF)</sub> =1.5V, T <sub>C</sub> =100°C	5				
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =9V, I <sub>C</sub> =0			1	mA	
SECOND BREAKDOWN							
Second Breakdown Collector Current	1			6.	ee Fig. 1	14	
with bass forward biased	I <sub>S/B</sub>			36	ee rig.	1 1	
Clamped Inductive SOA with Base	RBSOA			9	ae Fig. 1	12	
Reverse Biased	KBSOA			See Fig. 12			
ON CHARACTERISTICS (Note 1)	1	·					
	h <sub>FE1</sub>	I <sub>C</sub> =0.5A, V <sub>CE</sub> =5V	15		50		
DC Current Gain	h <sub>FE2</sub>	I <sub>C</sub> =1A, V <sub>CE</sub> =5V	10		60		
	h <sub>FE3</sub>	I <sub>C</sub> =2A, V <sub>CE</sub> =5V	8		40		
	V <sub>CE</sub> (SAT)	I <sub>C</sub> =1A, I <sub>B</sub> =0.2A			0.5	V	
Collector-Emitter Saturation Voltage		I <sub>C</sub> =2A, I <sub>B</sub> =0.5A			0.6	V	
Collector-Enlitter Saturation voltage		I <sub>C</sub> =4A, I <sub>B</sub> =1A			1	V	
		I <sub>C</sub> =2A, I <sub>B</sub> =0.5A, Ta=100°C			1	V	
	V <sub>BE (SAT)</sub>	I <sub>C</sub> =1A, I <sub>B</sub> =0.2A			1.2	V	
Base-Emitter Saturation Voltage		I <sub>C</sub> =2A, I <sub>B</sub> =0.5A			1.6	V	
		I <sub>C</sub> =2A, I <sub>B</sub> =0.5A, T <sub>C</sub> =100°C			1.5	V	
DYNAMIC CHARACTERISTICS							
Current-Gain-Bandwidth Product	f⊤	I <sub>C</sub> =500mA, V <sub>CE</sub> =10V, f=1MHz	4			MHz	
Output Capacitance	C <sub>OB</sub>	$V_{CB}$ =10V, $I_E$ =0, f=0.1MHz		65		pF	
SWITCHING CHARACTERISTICS							
Resistive Load (Table 1)							
Delay Time	$t_D$	_		0.025	0.1	μs	
Rise Time	$t_R$	$V_{CC}$ =125V, $I_{C}$ =2A, $I_{B1}$ = $I_{B2}$ =0.4A,		0.3	0.7	μs	
Storage Time	ts	t <sub>P</sub> =25µs, Duty Cycle≤1%		1.7	4	μs	
Fall Time	$t_{F}$			0.4	0.9	μs	

Note: 1. Pulse Test: Pulse Width=5ms, Duty Cycle≤10%

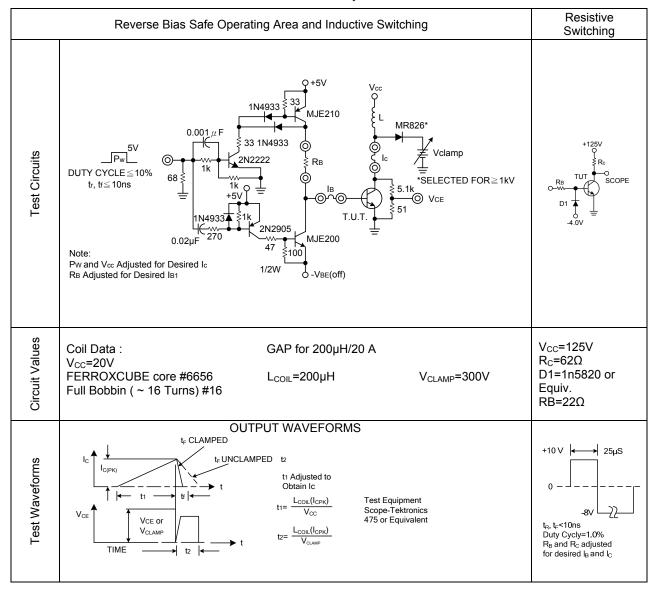
### ■ CLASSIFICATION OF h<sub>FE1</sub>

RANK	Α	В	С	C D	
RANGE	15 ~ 20	20 ~ 25	25 ~ 30	30 ~ 40	40 ~ 50

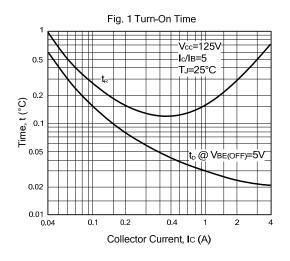
<sup>2.</sup> Pulse Test: P<sub>W</sub>=300µs, Duty Cycle≤2%

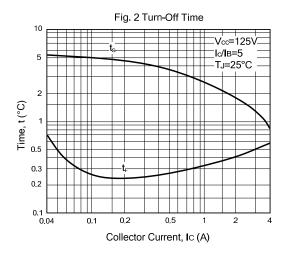
#### APPLICATION INFORMATION

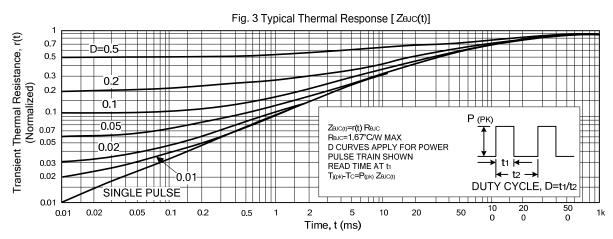
Table 1.Test Conditions for Dynamic Performance

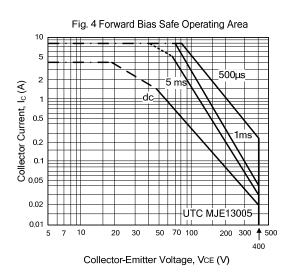


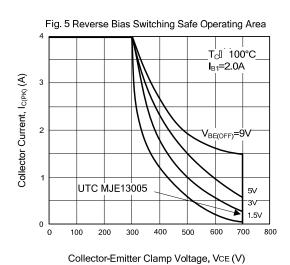
#### **■ RESISTIVE SWITCHING PERFORMANCE**



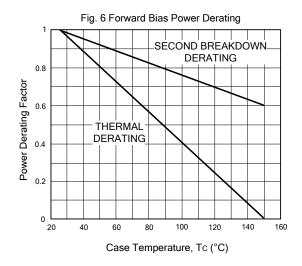








#### ■ RESISTIVE SWITCHING PERFORMANCE(Cont.)



#### SAFE OPERATING AREA INFORMATION

#### **FORWARD BIAS**

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I<sub>C</sub>-V<sub>CE</sub> limits of the transistor that must be observed for reliable operation; e., the transistor must not be subjected to greater dissipation than the curves indicate.

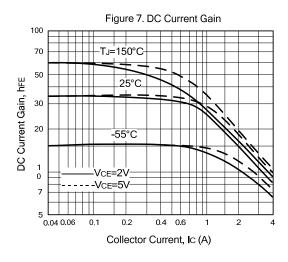
The data of Fig. 4 is based on  $T_C = 25^{\circ}C$ ;  $T_{J(PK)}$  is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated when  $T_C \ge 25^{\circ}C$ . Second breakdown limitations do not derate the same as thermal limitations. Allowable current at the voltages shown on Fig. 4 may be found at any case temperature by using the appropriate curve on Fig. 6.

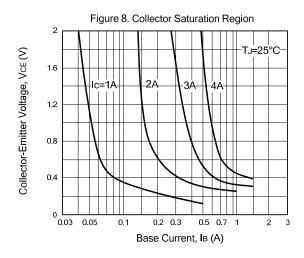
 $T_{J(PK)}$  may be calculated from the data in Fig. 10. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

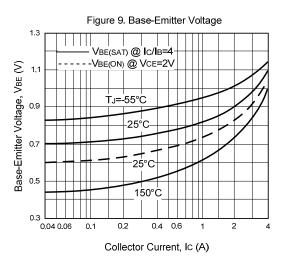
#### **REVERSE BIAS**

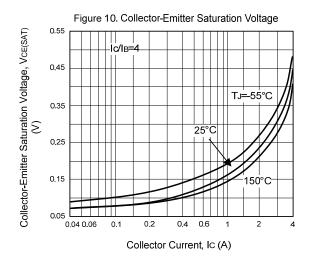
For inductive loads, high voltage and high current must be sustained simultaneously during turn-off, in most cases, with the base to emitter junction reverse biased. Under these conditions the collector voltage must be held to a safe level at or below a specific value of collector current. This can be accomplished by several means such as active clamping, RC snubbing, load line shaping, etc. The safe level for these devices is specified as Reverse Bias Safe Operating Area and represents the voltage-current conditions during reverse biased turn-off. This rating is verified under clamped conditions so that the device is never subjected to an avalanche mode. Figure 5 gives the complete RBSOA characteristics.

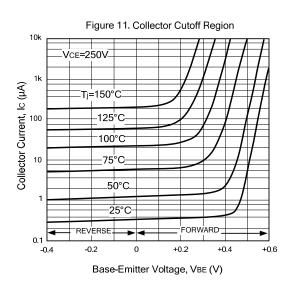
#### TYPICAL CHARACTERISTICS

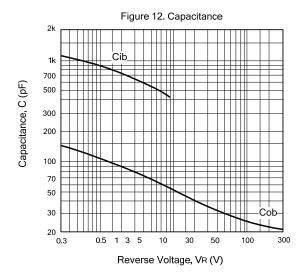












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